

# RGWX5TS65EHR

650V 75A Field Stop Trench IGBT

V <sub>CES</sub>	650V
I <sub>C (100°C)</sub>	75A
V <sub>CE(sat) (Typ.)</sub>	1.5V
P <sub>D</sub>	348W

#### Features

- 1) AEC-Q101 Qualified
- 2) Low Collector Emitter Saturation Voltage
- 3) Low Switching Loss & Soft Switching
- 4) Built in Very Fast & Soft Recovery FRD
- 5) Pb free Lead Plating ; RoHS Compliant

#### Application

Automotive

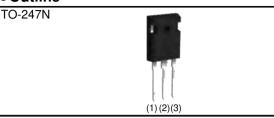
On & Off Board Chargers

**DC-DC Converters** 

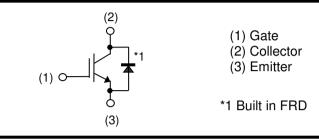
PFC

Industrial Inverter

#### Outline



#### Inner Circuit



#### Packaging Specifications

	Packaging	Tube
	Reel Size (mm)	-
Tuno	Tape Width (mm)	-
Туре	Basic Ordering Unit (pcs)	450
	Packing Code	C11
	Marking	RGWX5TS65E

### •Absolute Maximum Ratings (at T<sub>C</sub> = 25°C unless otherwise specified)

Parameter		Symbol	Value	Unit
Collector - Emitter Voltage		V <sub>CES</sub>	650	V
Gate - Emitter Voltage		V <sub>GES</sub>	±30	V
$T_c = 25^{\circ}C$		Ι <sub>C</sub>	132	Α
Collector Current	$T_{\rm C} = 100^{\circ}{\rm C}$	Ι <sub>C</sub>	81	А
Pulsed Collector Current		I <sub>CP</sub> *1	300	Α
Diode Forward Current	$T_{\rm C} = 25^{\circ}{\rm C}$	I <sub>F</sub>	127	А
	$T_{\rm C} = 100^{\circ}{\rm C}$	I <sub>F</sub>	80	А
Diode Pulsed Forward Current		I <sub>FP</sub> <sup>*1</sup>	300	Α
$T_c = 25^{\circ}C$		P <sub>D</sub>	348	W
Power Dissipation	$T_{\rm C} = 100^{\circ}{\rm C}$	P <sub>D</sub>	174	W
Operating Junction Temperature		T <sub>j</sub>	-40 to +175	°C
Storage Temperature		T <sub>stg</sub>	-55 to +175	°C

\*1 Pulse width limited by  $T_{jmax}$ 

#### •Thermal Resistance

Parameter	Symbol	Values			Unit
Farameter	Symbol	Min.	Тур.	Max.	Unit
Thermal Resistance IGBT Junction - Case	$R_{\theta(j-c)}$	-	-	0.43	°C/W
Thermal Resistance Diode Junction - Case	$R_{\theta(j-c)}$	-	-	0.57	°C/W

## ●IGBT Electrical Characteristics (at T<sub>j</sub> = 25°C unless otherwise specified)

Parameter	Symbol Conditions		Values			Unit
	Symbol	Conditions	Min.	Тур.	Max.	Onit
Collector - Emitter Breakdown Voltage	BV <sub>CES</sub>	$I_{\rm C}$ = 10µA, $V_{\rm GE}$ = 0V	650	-	_	V
Collector Cut - off Current	I <sub>CES</sub>	$V_{CE} = 650V, V_{GE} = 0V$	-	-	10	μA
Gate - Emitter Leakage Current	I <sub>GES</sub>	$V_{GE} = \pm 30V, V_{CE} = 0V$	-	-	±200	nA
Gate - Emitter Threshold Voltage	$V_{GE(th)}$	V <sub>CE</sub> = 5V, I <sub>C</sub> = 50.4mA	5.0	6.0	7.0	V
Collector - Emitter Saturation Voltage	V <sub>CE(sat)</sub>	$I_{C} = 75A, V_{GE} = 15V,$ $T_{j} = 25^{\circ}C$ $T_{j} = 175^{\circ}C$	-	1.5 1.85	1.9 -	V

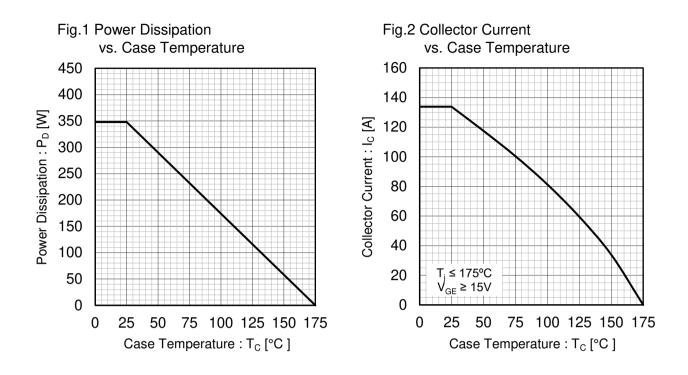
#### RGWX5TS65EHR

# •IGBT Electrical Characteristics (at $T_j = 25^{\circ}C$ unless otherwise specified)

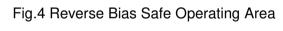
Parameter	Symbol Conditions		1.114				
		Conditions	Min.	Тур.	Max.	Unit	
Input Capacitance	C <sub>ies</sub>	$V_{CE} = 30V,$	-	5980	-		
Output Capacitance	C <sub>oes</sub>	$V_{GE} = 0V,$	-	156	-	pF	
Reverse transfer Capacitance	C <sub>res</sub>	f = 1MHz	-	118	-		
Total Gate Charge	Qg	V <sub>CE</sub> = 400V,	-	213	-		
Gate - Emitter Charge	$Q_{ge}$	I <sub>C</sub> = 75A,	-	42	-	nC	
Gate - Collector Charge	$Q_{gc}$	V <sub>GE</sub> = 15V	-	82	-		
Turn - on Delay Time	t <sub>d(on)</sub>		-	59	-		
Rise Time	t <sub>r</sub>	$I_{C} = 37.5A, V_{CC} = 400V, V_{GE} = 15V, R_{G} = 10\Omega,$	-	18	-	ns	
Turn - off Delay Time	$t_{d(off)}$	$T_j = 25^{\circ}C$	-	243	-		
Fall Time	t <sub>f</sub>	Inductive Load	-	35	-		
Turn - on Switching Loss	E <sub>on</sub>	*E <sub>on</sub> include diode reverse recovery	-	0.99	-	mJ	
Turn - off Switching Loss	E <sub>off</sub>	,	-	0.73	-	110	
Turn - on Delay Time	t <sub>d(on)</sub>		-	55	-		
Rise Time	t <sub>r</sub>	$I_{C} = 37.5A, V_{CC} = 400V,$ $V_{GE} = 15V, R_{G} = 10\Omega,$	-	18	-	- ns	
Turn - off Delay Time	t <sub>d(off)</sub>	$T_j = 175^{\circ}C$	-	278	-		
Fall Time	t <sub>f</sub>	Inductive Load	-	76	-		
Turn - on Switching Loss	E <sub>on</sub>	*E <sub>on</sub> include diode reverse recovery	-	0.95	-	mJ	
Turn - off Switching Loss	E <sub>off</sub>	,	-	0.99	-		
Reverse Bias Safe Operating Area	RBSOA	$\begin{split} I_{C} &= 300 \text{A}, \ V_{CC} = 520 \text{V}, \\ V_{P} &= 650 \text{V}, \ V_{GE} = 15 \text{V}, \\ R_{G} &= 100 \Omega, \ T_{j} = 175^{\circ} \text{C} \end{split}$	FU	ILL SQUA	RE	-	

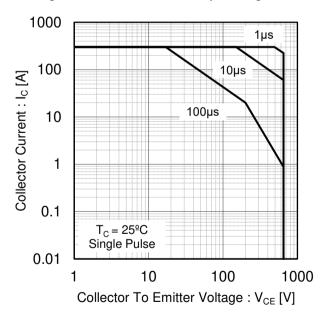
# •FRD Electrical Characteristics (at $T_j = 25^{\circ}C$ unless otherwise specified)

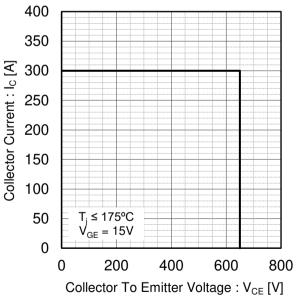
Parameter	Symbol	Conditions	Values			Unit
	Symbol		Min.	Тур.	Max.	Unit
		I <sub>F</sub> = 75A,				
Diode Forward Voltage	$V_{F}$	$T_j = 25^{\circ}C$	-	1.45	1.9	V
		T <sub>j</sub> = 175°C	-	1.55	-	
Diode Reverse Recovery Time	t <sub>rr</sub>		-	100	-	ns
Diode Peak Reverse Recovery Current	I <sub>rr</sub>	I <sub>F</sub> = 37.5A, V <sub>CC</sub> = 400V,	-	11.5	-	A
Diode Reverse Recovery Charge	Q <sub>rr</sub>	di <sub>F</sub> /dt = 200A/µs, T <sub>j</sub> = 25°C	-	0.64	-	μC
Diode Reverse Recovery Energy	E <sub>rr</sub>		-	26.0	-	μJ
Diode Reverse Recovery Time	t <sub>rr</sub>	I <sub>F</sub> = 37.5A, V <sub>CC</sub> = 400V, di <sub>F</sub> /dt = 200A/μs, T <sub>j</sub> = 175°C	-	194	-	ns
Diode Peak Reverse Recovery Current	I <sub>rr</sub>		-	16.7	-	A
Diode Reverse Recovery Charge	Q <sub>rr</sub>		-	1.93	-	μC
Diode Reverse Recovery Energy	E <sub>rr</sub>		-	113	-	μJ



## Fig.3 Forward Bias Safe Operating Area







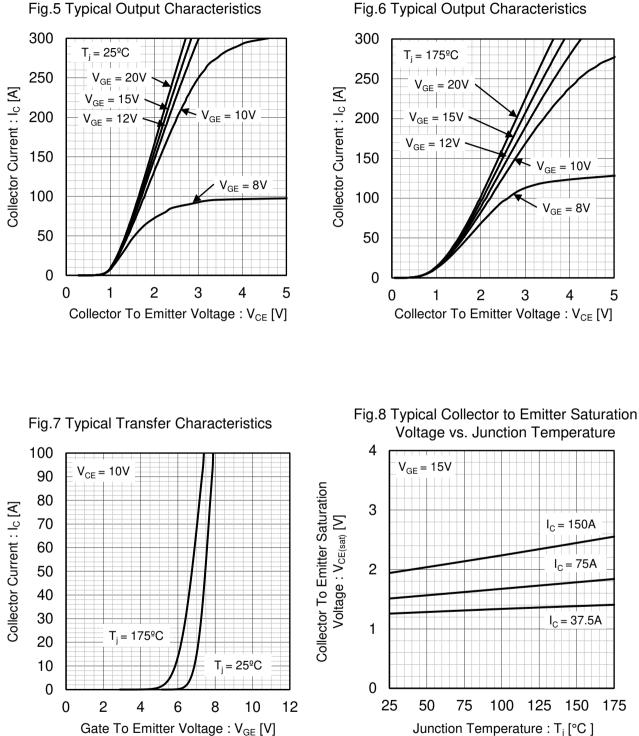
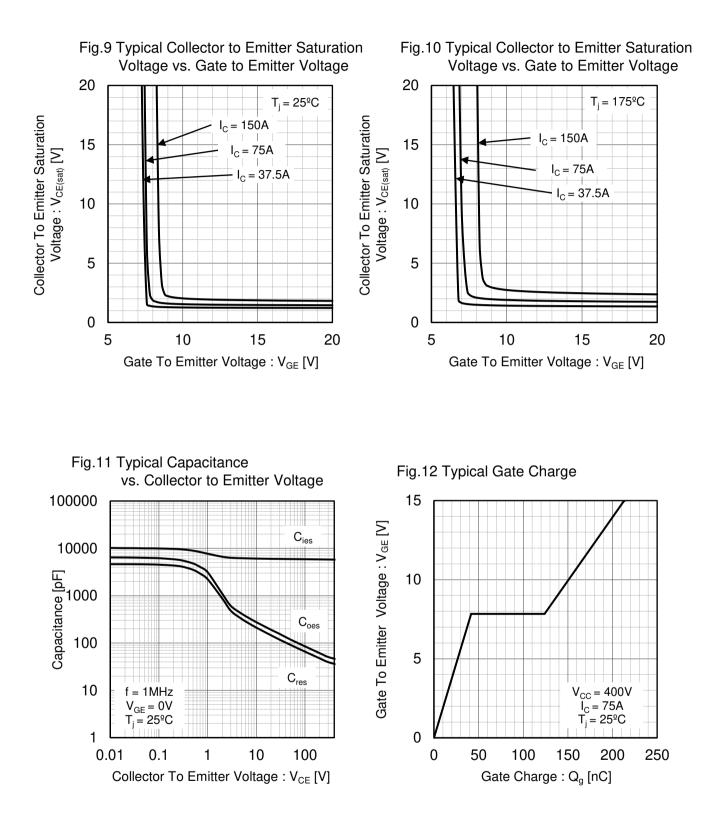
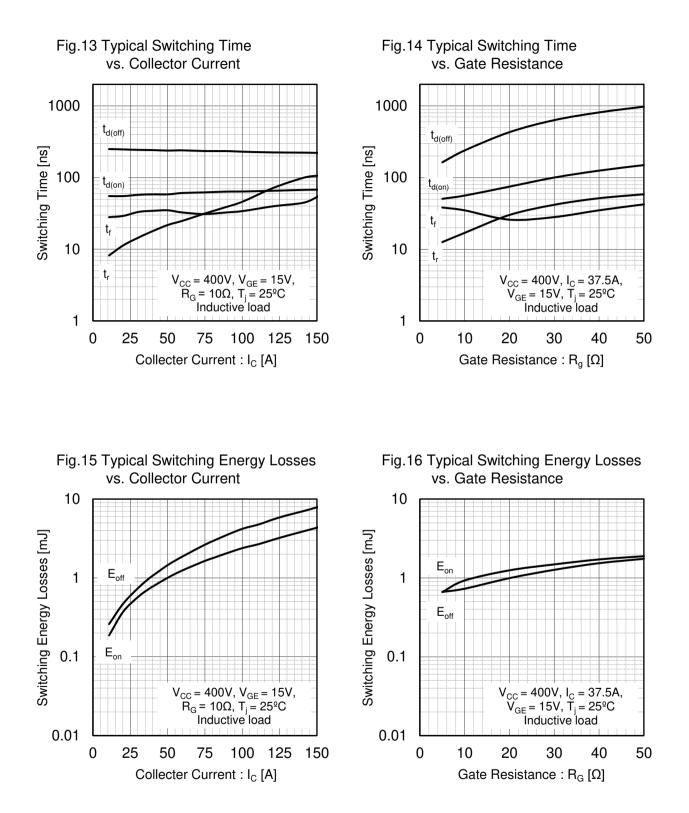
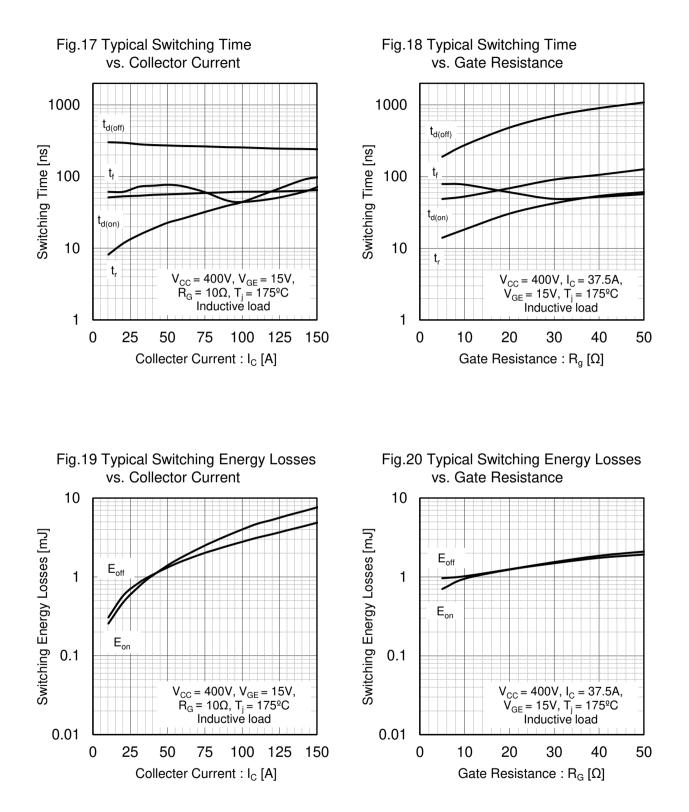


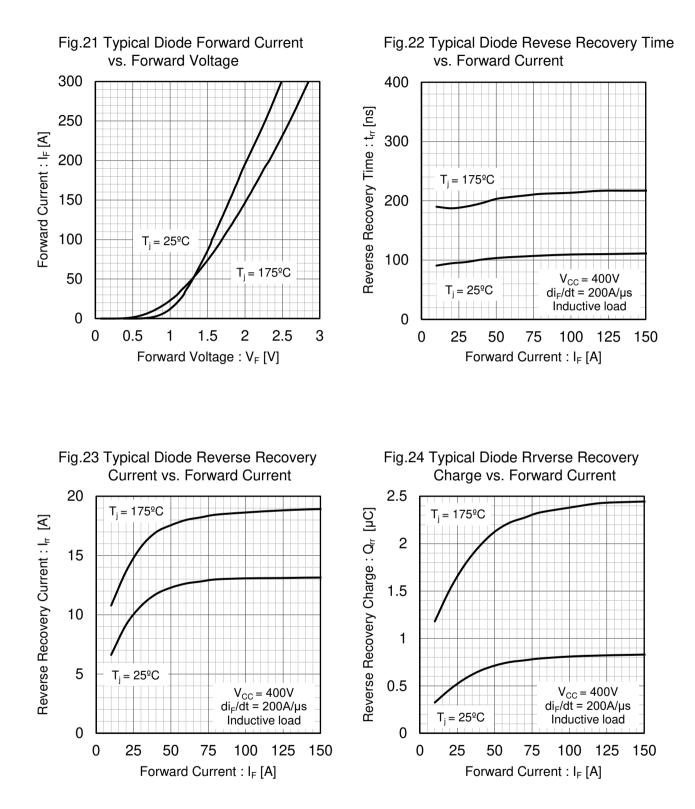
Fig.6 Typical Output Characteristics



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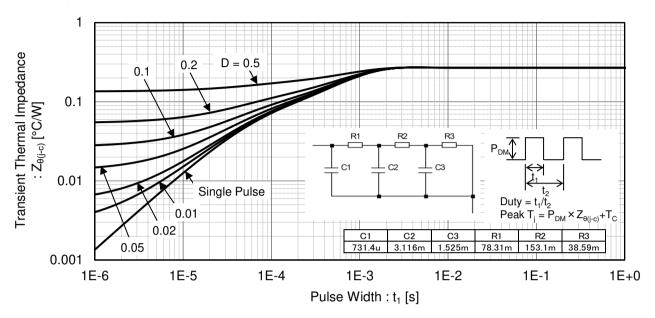
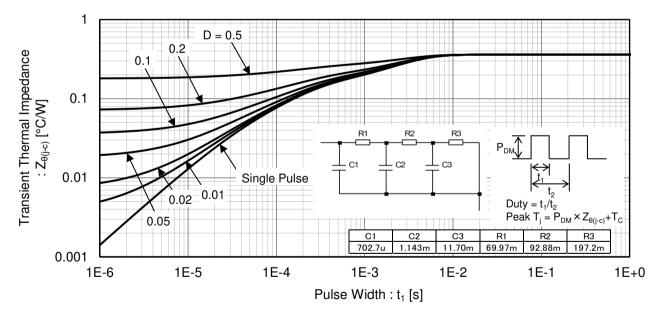


Fig.25 Typical IGBT Transient Thermal Impedance

Fig.26 Typical Diode Transient Thermal Impedance



#### Inductive Load Switching Circuit and Waveform

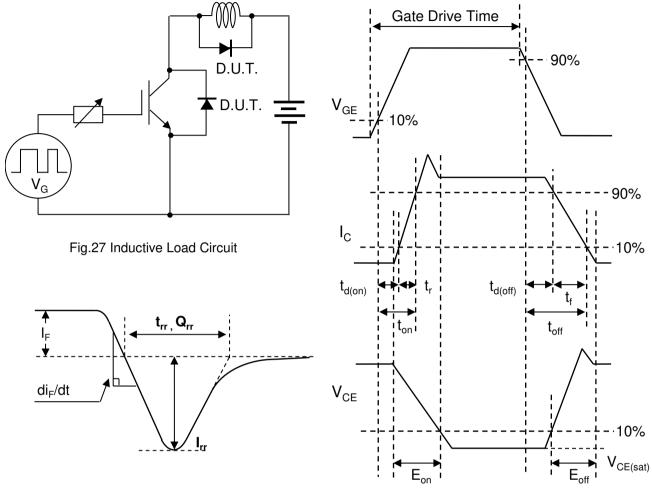


Fig.29 Diode Reverse Recovery Waveform

Fig.28 Inductive Load Waveform

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